

Weight (mg):

Part Number: BZX84Cxx-p-F (Date Code 0833+)

8.487

p = package designator

See Data Sheet

10, 11, 12, 13, 15, 16, 18, 20, 22, 24, 27, 2V4, 2V7, 30, 33, 36, 39, 3V0, 3V3, 3V6, 3V9, 4V3, 4V7, 5V4, 5V6, 6V2, 6V2, 7V5, 8V2, 0V4

Element	Material Group	Materials	CAS (if applicable)	Average mass homogeneous Materal(%)		Mass (mg)	ppm Homogeneous Material	ppm overall
Chip	Silicon w/Metal	Doped Silicon*	7440-21-3	100.00%	0.76%	0.0647	1000000	762
Leadframe		Fe	7439-89-6	57.65%	- 28.79%	2.4432	576500	16595
		Ni	7440-02-0	41.00%			410000	11802
	Alloy 42	Mn	7439-96-5	0.60%			6000	172
	Alloy 42	Cr(not Cr 6+)	7440-47-3	0.10%			1000	28
		Со	7440-48-4	0.50%			5000	143
		Si	7440-21-3	0.15%			1500	43:
Leadframe Plating	Silver	Silver	7440-22-4	100.00%	1.22%	0.1034	1000000	1218
Bond Wire	Gold Wire	Gold	7440-57-5	100.00%	0.10%	0.0082	1000000	96
Encapsulation		SiO2	60676-86-0	69.00%	- 66.13%	5.6124	690000	45627
		Epoxy Resin	29690-82-2	14.00%			140000	9257
	KTMC-1050G	Phenol Resin	9003-35-4	7.00%			70000	4628
	K1101C-1050G	Mg(OH)2	1309-42-8	8.00%			80000	5290
		С	1333-86-4	0.20%			2000	132
		others		1.80%			18000	1190
ead Plating Finish	Matte Tin	Tin	7440-31-5	100.00%	3.01%	0.2555	1000000	3010
				Total	100.00	8.4874		100000

Tolerance ±10%

This data is based on information provided by our suppliers. We believe it to be correct but do not routinely validate it by measurement. It is for guidance only and Diodes Inc. does not guarantee its absolute accuracy or completeness

This product or product family does not contain any of the following substances except as CURRENTLY exempted by ELV II and RoHS and reported above:

Asbestos Azo compounds

Azo compounds
Cadmium and cadmium compounds
Certain Shortchain Chlorinated Paraffins
Chlorinated organic compounds
Hexavalent chromium compounds
Lead and lead compounds
Mercury and mercury compounds
Organic tin compounds

Ozone Depleting Substances - Class I (CFCs, HBFCs, etc.)

Ozone Depleting Substances - Class II (HCFCs)
Perfluorooctane Sulphonate (PFOS) or related compounds

Polybrominated biphenyls (PBB) and Polybrominated diphenyl ethers (PBDE) includin**DecaBDE**

Polychlorinated Biphenyls (PCBs)

Polychlorinated Naphthalenes (> 3 chlorine atoms)

Radioactive Substances

Tributyl Tin (TBT) and Triphenyl Tin (TPT)

Tributyl Tin Oxide (TBTO)

^{*} The Silicon Chip is doped at atomic levels with trace amounts of elements that may include Phosphorus, Boron, Arsenic, and other elements. Metalization may include Titanium, Nickel, Aluminum, Silver or Gold These substances are not reported where their concentration is less than the minimum reportable level per the guidelines specified in the Tables of EIA JIG-101, <u>Material Composition Declaration for Electronic Products</u>.